SCBS680A - MARCH 1997 - REVISED MAY 1997

- Outputs Have Equivalent 25-Ω Series Resistors, So No External Resistors Are Required
- State-of-the-Art *EPIC-*II*B*[™] BiCMOS Design Significantly Reduces Power Dissipation
- High-Impedance State During Power Up and Power Down
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- ESD Protection Exceeds 2000 V Per MIL-STD-833, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Thin Very Small-Outline (DGV) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

description

These octal transceivers and line drivers are designed for asynchronous communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

SN54ABTR2245 . . . J PACKAGE SN74ABTR2245 . . . DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)

	(,	
DIR		J ₂₀	v _{cc}
A1	2	19] OE
A2	3	18] B1
A3	4	17	B2
A4	5	16] B3
A5		15] B4
A6	7	14] B5
A7	8	13] B6
A8	9	12	B7
GND	10	11] B8

SN54ABTR2245 . . . FK PACKAGE (TOP VIEW)

	A2 DIR OE	
1		
A3] 4 ³ ² ¹ ²⁰ ¹³ 18 [] E	31
A4] 5 17 🚺 E	32
A3 A4 A5 A6 A7] 6 16 🛛 E	33
A6	7 15 E	34
A7	8 14 🛛 E	35
ľ	GND B8 B7 B7 B7	

Both the A-port and B-port outputs, which are designed to sink up to 12 mA, include equivalent 25Ω series resistors to reduce overshoot and undershoot.

When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABTR2245 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABTR2245 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE								
INP	UTS	OPERATION						
OE	DIR	OPERATION						
L	L	B data to A bus						
L	Н	A data to B bus						
Н	Х	Isolation						



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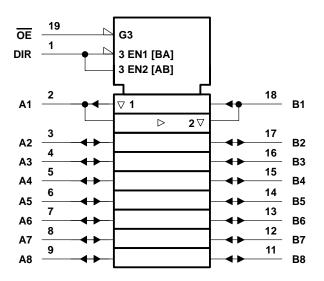
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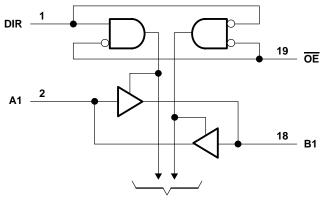
SCBS680A - MARCH 1997 - REVISED MAY 1997

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

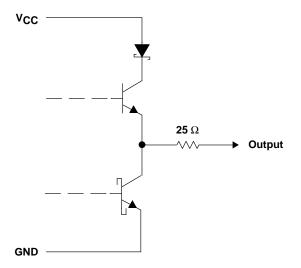


To Seven Other Channels



SCBS680A - MARCH 1997 - REVISED MAY 1997

output schematic



All resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, VI (except I/O ports) (see N		
Voltage range applied to any output in the high	or power-off state, VO	. –0.5 V to 5.5 V
Current into any output in the low state, IO		30 mA
Input clamp current, I _{IK} (V _I < 0)		–18 mA
Output clamp current, I _{OK} (V _O < 0)		–50 mA
Package thermal impedance, θ_{JA} (see Note 2):	DB package	115°C/W
	DGV package	146°C/W
	DW package	97°C/W
	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.



SCBS680A - MARCH 1997 - REVISED MAY 1997

recommended operating conditions (see Note 3)

						SN74ABTR2245	
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage			5.5	4.5	5.5	V
VIH	High-level input voltage		2	h.	2		V
VIL	Low-level input voltage		0.8		0.8	V	
VI	Input voltage	0	Vcc	0	VCC	V	
ЮН	High-level output current			-12		-12	mA
IOL	Low-level output current	w-level output current		12		12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate Outputs enabled		^y o ^y	5		5	ns/V
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		Q 200		200		μs/V
Т _А	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.



SCBS680A - MARCH 1997 - REVISED MAY 1997

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	AMETED	TEST CON		т	'A = 25°C	25°C SN54ABTR2245 S		SN74ABTR2245		UNIT		
FAR	RAMETER	TEST CON	IDITIONS	MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNIT	
VIK		V _{CC} = 4.5 V,	lj = -18 mA			-1.2		-1.2		-1.2	V	
		V _{CC} = 4.5 V,	I _{OH} = -1 mA	3.35			3.3		3.35			
Vari		$V_{CC} = 5 V,$	I _{OH} = -1 mA	3.85			3.8		3.85		v	
VOH		V _{CC} = 4.5 V	I _{OH} = -3 mA				3		3.1		v	
		VCC = 4.3 V	I _{OH} = -12 mA	2.6					2.6			
VOL		V _{CC} = 4.5 V	I _{OL} = 8 mA			0.65		0.8		0.65	V	
VOL		VCC = 4.3 V	I _{OL} = 12 mA			0.8				0.8		
V _{hys}					100						mV	
1.	Control inputs	$V_{CC} = 0$ to 5.5 V, $V_I = V_{CC}$ or GND				±1		±1		±1	μA	
łı	A or B ports	$V_{CC} = 2.1 V \text{ to } 5.5 V_{I} = V_{CC} \text{ or GND}$	Ι,			±20		±20		±20	μΑ	
Iozh‡		$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 5.5 \text{ V}$	/, V _O = 2.7 V,			10		J 10		10		
I _{OZL} ‡		$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 5.5 \text{ V}$	/, V _O = 0.5 V,			-10	Cro.	-10	-10		μΑ	
IOZPU [§]	3	$\frac{V_{CC}}{OE} = 0 \text{ to } 2.1 \text{ V}, \text{ V}_{CC}$) = 0.5 V to 2.7 V,			±50	PODU	±50	±50		μA	
IOZPD§	}	$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 0, \text{ V}_{CC}$			±50	Q	±50		±50	μA		
loff		V _{CC} = 0,	$V_{I} \text{ or } V_{O} \leq 4.5 \text{ V}$			±100				±100	μΑ	
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	μΑ	
۱o¶		V _{CC} = 5.5 V,	V _O = 2.5 V	-25		-100	-25	-100	-25	-100	mA	
-		V _{CC} = 5.5 V,	Outputs high		1	250		250		250	μA	
ICC	A or B ports	$I_{O} = 0,$	Outputs low		24	32		32		32	mA	
		$V_I = V_{CC} \text{ or } GND$	Outputs disabled		0.5	250		250		250	μΑ	
	Data inputs		V _{CC} = 5.5 V, One input at 3.4 V,	Outputs enabled			1.5		1.5		1.5	
∆ICC [#]		' Other inputs at	Outputs disabled			0.05		0.05		0.05	mA	
	Control inputs	V_{CC} = 5.5 V, One in Other inputs at V_{CC}				1.5		1.5		1.5		
Ci		V _I = 2.5 V or 0.5 V			3						pF	
Cio		V _O = 2.5 V or 0.5 V			6						pF	

* On products compliant to MIL-PRF-38535, this parameter does not apply.

[†] All typical values are at $V_{CC} = 5 V$. [‡] The parameters I_{OZH} and I_{OZL} include the input leakage current.

§ This parameter is characterized but not production tested.

I Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[#]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



SCBS680A - MARCH 1997 - REVISED MAY 1997

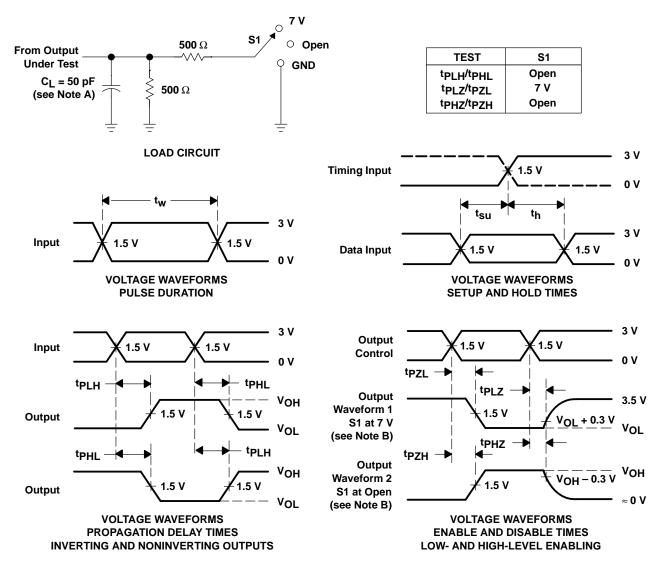
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			SN54ABTR2245		SN74ABTR2245		UNIT
		(001-01)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
^t PLH	A or B	B or A	1	2.5	3.4	1	4	1	3.8	ns
^t PHL			1	3.2	4.2	1	4.6	1	4.5	
^t PZH	OE	A or B	1.5	3.6	4.9	1.5	6.3	1.5	6.1	ns
^t PZL	OE	AUB	1.5	3.9	5.3	1.5	6.6	1.5	6.3	115
^t PHZ	ŌĒ	A or B	1.5	3.6	4.7	0 1.5	5.5	1.5	5.3	ns
^t PLZ		AUB	1.5	3.3	4.4	2 1.5	4.9	1.5	4.8	115

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SCBS680A - MARCH 1997 - REVISED MAY 1997



PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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